

### Vishay General Semiconductor

## **High-Voltage Surface Mount Schottky Rectifier**

High Barrier Technology for improved high temperature performance



DO-214AC (SMA)

MAJOR RATINGS AND CHARACTERISTICS					
I <sub>F(AV)</sub>	1.0 A				
V <sub>RRM</sub>	90 V to 100 V				
I <sub>FSM</sub>	50 A				
$V_{F}$	0.62 V				
I <sub>R</sub>	1.0 μΑ				
T <sub>j</sub> max.	175 °C				

#### **FEATURES**

· Low profile package



- Ideal for automated placement
- Guardring for overvoltage protection
- · Low power losses, high efficiency
- · Low forward voltage drop
- · Low leakage current
- · High surge capability
- Meets MSL level 1, per J-STD-020C, LF max peak of 260 °C
- Solder Dip 260 °C 40 seconds
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

#### **MECHANICAL DATA**

Case: DO-214AC (SMA)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high

reliability grade (AEC Q101 qualified)

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS1H9	SS1H10	UNIT	
Device marking code		S9	S10		
Maximum repetitive peak reverse voltage	$V_{RRM}$	90 100		V	
Working peak reverse voltage	V <sub>RWM</sub>	90 100		V	
Maximum DC blocking voltage	$V_{DC}$	90 100		V	
Maximum average forward rectified current (see Fig. 1)	I <sub>F(AV)</sub>	1.0		Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50		Α	
Peak repetitive reverse surge current at $t_p$ = 2.0 $\mu$ s, 1 kHz	I <sub>RRM</sub>	1.0		Α	
Storage temperature range	T <sub>STG</sub>	- 65 to + 175		°C	
Maximum operating temperature	T <sub>J</sub>	175		°C	

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS	SYMBOL	SS1H9	SS1H10	UNIT
Maximum instantaneous forward voltage at: (1)	$\begin{aligned} I_F &= 1.0 \text{ A}, & T_j &= 25 ^\circ\text{C} \\ I_F &= 1.0 \text{ A}, & T_j &= 125 ^\circ\text{C} \\ I_F &= 2.0 \text{ A}, & T_j &= 25 ^\circ\text{C} \\ I_F &= 2.0 \text{ A}, & T_j &= 125 ^\circ\text{C} \end{aligned}$	V <sub>F</sub>	0. 0. 0. 0.	62	V
Maximum DC reverse current at rated DC blocking voltage <sup>(1)</sup>	T <sub>j</sub> = 25 °C T <sub>j</sub> = 125 °C	I <sub>R</sub>	1.0 0.5		μA mA

#### Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	METER SYMBOL SS1H9 S			
Maximum thermal resistance (1)	$R_{ hetaJA} \ R_{ hetaJL}$	88 30		°C/W

#### Note:

(1) P.C.B. mounted with 0.2 x 0.2" (5.0 x 5.0 mm) copper pad areas

ORDERING INFORMATION					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS1H10-E3/61T	0.064	61T	1800	7" Diameter Plastic Tape & Reel	
SS1H10-E3/5AT	0.064	5AT	7500	13" Diameter Plastic Tape & Reel	

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

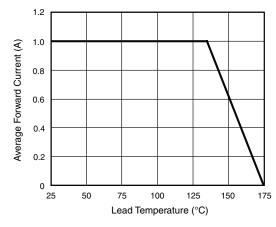


Figure 1. Forward Current Derating Curve

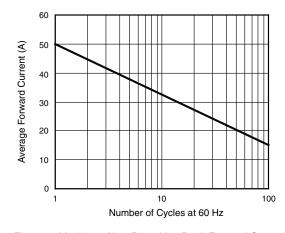


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

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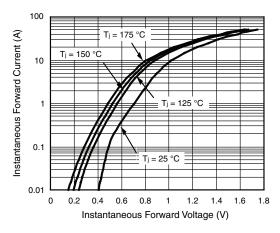


Figure 3. Typical Instantaneous Forward Characteristics

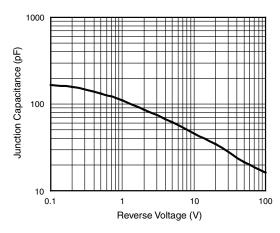


Figure 5. Typical Junction Capacitance

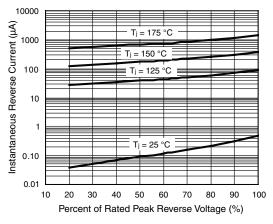


Figure 4. Typical Reverse Characteristics

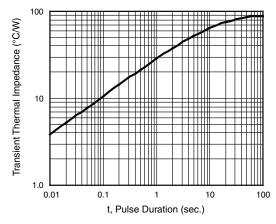
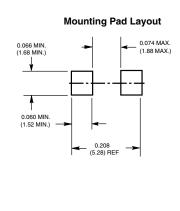


Figure 6. Typical Transient Thermal

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

## 0.065 (1.65) 0.049 (1.25) 0.090 (2.29) 0.090 (2.29) 0.090 (1.52) 0.090 (0.203) 0.090 (0.203) 0.090 (0.203) 0.090 (0.203) 0.090 (0.203) 0.090 (0.203) 0.090 (0.203)



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